

Vishay Semiconductors

HALOGEN

GREEN

(5-2008)

## Infrared Emitting Diode, 950 nm, GaAs



#### **DESCRIPTION**

TSUS5400 is an infrared, 950 nm emitting diode in GaAs technology molded in a blue-gray tinted plastic package.

#### **FEATURES**

· Package type: leaded • Package form: T-1% • Dimensions (in mm): Ø 5

· Leads with stand-off

• Peak wavelength:  $\lambda_p = 950 \text{ nm}$ 

· High reliability

• Angle of half intensity:  $\varphi = \pm 22^{\circ}$ 

· Low forward voltage

· Suitable for high pulse current operation

· Good spectral matching with Si photodetectors

· Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

### **APPLICATIONS**

- · Infrared remote control and free air transmission systems with low forward voltage and small package requirements
- · Emitter in transmissive sensors
- · Emitter in reflective sensors

PRODUCT SUMMARY					
COMPONENT	I <sub>e</sub> (mW/sr)	φ <b>(°)</b>	$λ_p$ (nm)	t <sub>r</sub> (ns)	
TSUS5400	14	± 22	950	800	
TSUS5401	17	± 22	950	800	
TSUS5402	20	± 22	950	800	

#### Note

· Test conditions see table "Basic Characteristics"

ORDERING INFORMATION					
ORDERING CODE	PACKAGING	REMARKS	PACKAGE FORM		
TSUS5400	Bulk	MOQ: 4000 pcs, 4000 pcs/bulk	T-1¾		
TSUS5401	Bulk	MOQ: 4000 pcs, 4000 pcs/bulk	T-1¾		
TSUS5402	Bulk	MOQ: 4000 pcs, 4000 pcs/bulk	T-1¾		

### Note

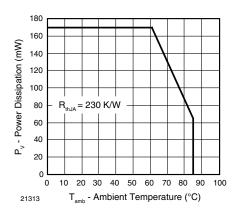
MOQ: minimum order quantity

<b>ABSOLUTE MAXIMUM RATINGS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified)					
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT	
Reverse voltage		$V_{R}$	5	V	
Forward current		I <sub>F</sub>	150	mA	
Peak forward current	$t_p/T = 0.5, t_p = 100 \mu s$	I <sub>FM</sub>	300	mA	
Surge forward current	t <sub>p</sub> = 100 μs	I <sub>FSM</sub>	2.5	Α	
Power dissipation		PV	170	mW	
Junction temperature		Tj	100	°C	
Operating temperature range		T <sub>amb</sub>	- 40 to + 85	°C	
Storage temperature range		T <sub>stg</sub>	- 40 to + 100	°C	
Soldering temperature	t ≤ 5 s, 2 mm from case	T <sub>sd</sub>	260	°C	
Thermal resistance junction/ambient	J-STD-051, leads 7 mm, soldered on PCB	R <sub>thJA</sub>	230	K/W	



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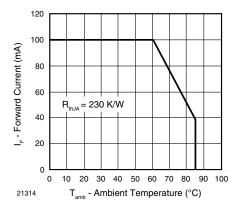


Fig. 1 - Power Dissipation Limit vs. Ambient Temperature

Fig. 2 - Forward Current Limit vs. Ambient Temperature

BASIC CHARACTERISTICS (T <sub>amb</sub> = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	IIN. TYP. MAX.		UNIT
Forward voltage	$I_F = 100 \text{ mA}, t_p = 20 \text{ ms}$	V <sub>F</sub>		1.3	1.7	V
Temperature coefficient of V <sub>F</sub>	I <sub>F</sub> = 100 mA	TK <sub>VF</sub>		- 1.3		mV/K
Reverse current	V <sub>R</sub> = 5 V	I <sub>R</sub>			100	μA
Junction capacitance	$V_R = 0 \text{ V, } f = 1 \text{ MHz, } E = 0$	C <sub>j</sub>		30		pF
Temperature coefficient of φ <sub>e</sub>	I <sub>F</sub> = 20 mA	TKφ <sub>e</sub>		- 0.8		%/K
Angle of half intensity		φ		± 22		٥
Peak wavelength	I <sub>F</sub> = 100 mA	λρ		950		nm
Spectral bandwidth	I <sub>F</sub> = 100 mA	Δλ		50		nm
Temperature coefficient of $\lambda_p$	I <sub>F</sub> = 100 mA	TKλ <sub>p</sub>		0.2		nm/K
Dia attenda	I <sub>F</sub> = 100 mA	t <sub>r</sub>		800		ns
Rise time	I <sub>F</sub> = 1.5 A	t <sub>r</sub>		400		ns
Fall time	I <sub>F</sub> = 100 mA	t <sub>f</sub>		800		ns
Fall time	I <sub>F</sub> = 1.5 A	t <sub>f</sub>		400		ns
Virtual source diameter		d		2.9		mm

TYPE DEDICATED CHARACTERISTICS (T <sub>amb</sub> = 25 °C, unless otherwise specified)							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
Forward voltage	I <sub>F</sub> = 1.5 A, t <sub>p</sub> = 100 μs	TSUS5400	V <sub>F</sub>		2.2	3.4	V
		TSUS5401	$V_{F}$		2.2	3.4	V
		TSUS5402	$V_{F}$		2.2	2.7	V
		TSUS5400	l <sub>e</sub>	7	14	35	mW/sr
	$I_F = 100 \text{ mA}, t_p = 20 \text{ ms}$	TSUS5401	l <sub>e</sub>	10	17	35	mW/sr
Dadient intensity		TSUS5402	l <sub>e</sub>	15	20	35	mW/sr
Radiant intensity		TSUS5400	l <sub>e</sub>	60	140		mW/sr
	$I_F = 1.5 \text{ A}, t_p = 100 \mu \text{s}$	TSUS5401	l <sub>e</sub>	85	160		mW/sr
		TSUS5402	l <sub>e</sub>	120	190		mW/sr
		TSUS5400	φ <sub>e</sub>		13		mW
Radiant power	$I_F = 100 \text{ mA}, t_p = 20 \text{ ms}$	TSUS5401	фе		14		mW
		TSUS5402	φ <sub>e</sub>		15		mW

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### **BASIC CHARACTERISTICS** (T<sub>amb</sub> = 25 °C, unless otherwise specified)

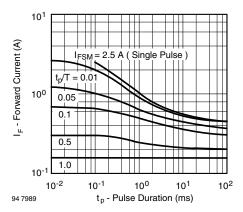


Fig. 3 - Pulse Forward Current vs. Pulse Duration

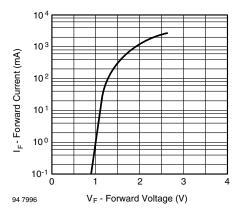


Fig. 4 - Forward Current vs. Forward Voltage

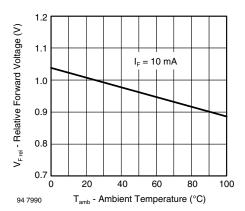


Fig. 5 - Relative Forward Voltage vs. Ambient Temperature

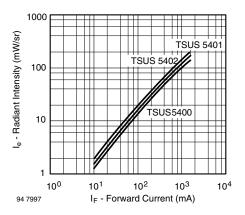


Fig. 6 - Radiant Intensity vs. Forward Current

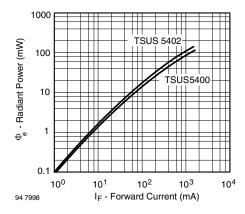


Fig. 7 - Radiant Power vs. Forward Current

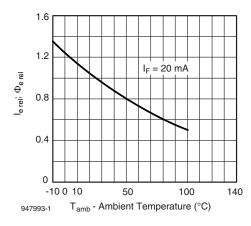


Fig. 8 - Relative Radiant Intensity/Power vs. Ambient Temperature



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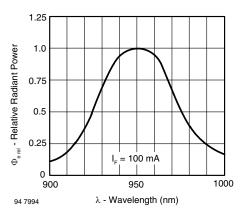


Fig. 9 - Relative Radiant Power vs. Wavelength

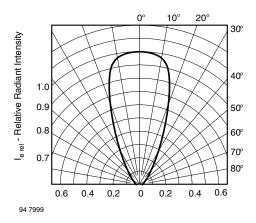
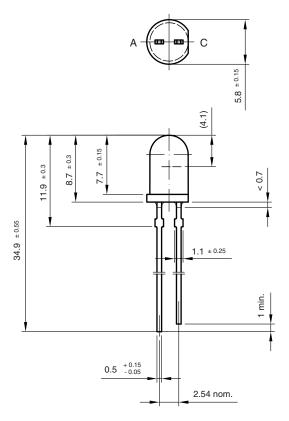
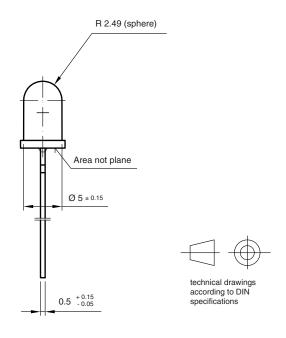


Fig. 10 - Relative Radiant Intensity vs. Angular Displacement

### **PACKAGE DIMENSIONS** in millimeters



6.544-5258.01-4 Issue: 5; 19.05.09 96 12119



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